



2829

PTO/SB/21 (08-00)

TRANSMITTAL FORM <i>(to be used for all correspondence after initial filing)</i>	Application Number	09/699,466	
	Filing Date	October 31, 2000	
	First Named Inventor	Shunpei YAMAZAKI et al.	
	Group Art Unit	2829	
	Examiner Name	A. Sarkar	
Total Number of Pages in This Submission		Attorney Docket Number	0756-2222

ENCLOSURES (check all that apply)		
<input type="checkbox"/> Fee Transmittal Form <input type="checkbox"/> Fee Attached <input checked="" type="checkbox"/> Amendment / Reply <input checked="" type="checkbox"/> After Final <input type="checkbox"/> Affidavits/declaration(s) <input type="checkbox"/> Extension of Time Request <input type="checkbox"/> Express Abandonment Request <input type="checkbox"/> Information Disclosure Statement <input type="checkbox"/> Certified Copy of Priority Document(s) <input type="checkbox"/> Response to Missing Parts/Incomplete Application <input type="checkbox"/> Response to Missing Parts under 37 CFR 1.52 or 1.53	<input type="checkbox"/> Assignment Papers (for an Application) <input type="checkbox"/> Drawing(s) <input type="checkbox"/> Declaration and Power of Attorney <input type="checkbox"/> Licensing-related Papers <input type="checkbox"/> Petition <input type="checkbox"/> Petition to Convert to a Provisional Application <input type="checkbox"/> Power of Attorney, Revocation Change of Correspondence Address <input type="checkbox"/> Terminal Disclaimer <input type="checkbox"/> Request for Refund <input type="checkbox"/> CD, Number of CD(s) _____	<input type="checkbox"/> After Allowance Communication to Group <input type="checkbox"/> Appeal Communication to Board of Appeals and Interferences <input type="checkbox"/> Appeal Communication to Group (Appeal Notice, Brief, Reply Brief) <input type="checkbox"/> Proprietary Information <input type="checkbox"/> Status Letter <input type="checkbox"/> Other Enclosures 1. 2. 3. 4. 5. 6.
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Firm or Individual name	Eric J. Robinson Robinson Intellectual Property Law Office, P.C. PMB 955 21010 Southbank Street Potomac Falls, VA 20165
Signature	
Date	6-27-02

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#15/Amot. J
Shawn
7-24-02

In re Patent Application of) Art Unit: 2829
Shunpei YAMAZAKI et al.) Examiner: A. Sarkar
Serial No. 09/699,466)
Filed: October 31, 2000)
For: MEHTOD FOR FABRICATING A)
A SEMICONDUCTOR DEVICE)

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SUPPLEMENTAL AMENDMENT

Honorable Commissioner of Patents
Washington, D.C. 20231

Sir:

Further to the Amendment filed on May 20, 2002 please amend the above-
identified application as follows:

IN THE CLAIMS:

Please amend claims 10, 19, 20 and 25 as follows:

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~~10. (Amended) A method according to claim 7, wherein said crystallization
promoting material is selected from the group consisting of Fe, Co, Ni, Ru, Rh, Pd, Os,
Ir, Pt, Cu and Au.~~

~~19. (Amended) A method according to claim 15, wherein said crystallization
promoting material is selected from the group consisting of Fe, Co, Ni, Ru, Rh, Pd, Os,
Ir, Pt, Cu and Au.~~

~~20. (Twice Amended) A method for manufacturing a semiconductor device
comprising the steps of:
forming a semiconductor film on an insulating surface;
providing a crystallization promoting material onto said semiconductor film;~~